

# **Thyristor Module**

 $V_{RRM} = 2x 1600 V$ 

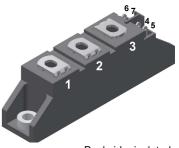
 $I_{TAV} = 50 A$ 

 $V_T = 1.17 V$ 

### Phase leg

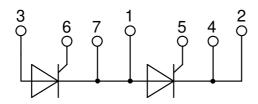
#### Part number

#### MCMA50P1600TA



Backside: isolated





#### Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability
- Direct Copper Bonded Al2O3-ceramic

#### **Applications:**

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

#### Package: TO-240AA

- Isolation Voltage: 4800 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

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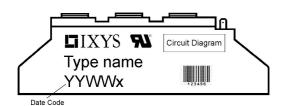


Thyristo		0			Ratings		
Symbol	Definition	Conditions	T 0500	min.	typ.	max.	Un
V <sub>RSM/DSM</sub>	max. non-repetitive reverse/forwa		$T_{VJ} = 25^{\circ}C$			1700	
V <sub>RRM/DRM</sub>	max. repetitive reverse/forward bloom		$T_{VJ} = 25^{\circ}C$			1600	'
I <sub>R/D</sub>	reverse current, drain current	$V_{R/D} = 1600 \text{ V}$	$T_{VJ} = 25^{\circ}C$			100	μ
		$V_{R/D} = 1600 \text{ V}$	$T_{VJ} = 140$ °C			6	m
V <sub>T</sub>	forward voltage drop	$I_T = 50 \text{ A}$	$T_{VJ} = 25^{\circ}C$			1.25	,
		I <sub>⊤</sub> = 100 A				1.48	'
		$I_{T} = 50 \text{ A}$	$T_{VJ} = 125$ °C			1.17	,
		$I_{T} = 100 \text{ A}$				1.44	,
I <sub>TAV</sub>	average forward current	T <sub>C</sub> = 85°C	T <sub>vJ</sub> = 140°C			50	1
I <sub>T(RMS)</sub>	RMS forward current	180° sine				79	
V <sub>T0</sub>	threshold voltage		$T_{VJ} = 140$ °C			0.89	,
r <sub>T</sub>	slope resistance } for power lo	ess calculation only				5.3	m۵
R <sub>thJC</sub>	thermal resistance junction to cas	e				0.7	K/V
R <sub>thCH</sub>	thermal resistance case to heatsin	nk			0.2		K/V
P <sub>tot</sub>	total power dissipation		T <sub>C</sub> = 25°C			160	٧
I <sub>TSM</sub>	max. forward surge current	t = 10 ms; (50 Hz), sine	$T_{V,I} = 45^{\circ}C$			800	,
- 1 3M	<u> </u>	t = 8.3  ms; (60 Hz), sine	$V_R = 0 V$			865	
		t = 10  ms; (50  Hz),  sine	T <sub>v,i</sub> = 140°C			680	
		t = 8.3  ms; (60 Hz), sine	$V_R = 0 V$			735	
l²t	value for fusing	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			3.20	!
	value for rushing	t = 8,3  ms; (60 Hz), sine	$V_R = 0 V$			3.12	l l
		t = 0.5  ms; (60 Hz), sine t = 10  ms; (50 Hz), sine	$V_R = 0 V$ $T_{V,I} = 140 ^{\circ}C$			2.31	kA <sup>2</sup>
		• • • • • • • • • • • • • • • • • • • •	• •				į
_	iunation canacitana	t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$		20	2.25	!
C,	junction capacitance	V <sub>R</sub> = 400 V f = 1 MHz	$T_{VJ} = 25^{\circ}C$		32	10	pl
$P_{GM}$	max. gate power dissipation	$t_P = 30 \mu s$	$T_{C} = 140^{\circ}C$			10	۷
_		$t_{P} = 300 \mu s$				5	۷
P <sub>GAV</sub>	average gate power dissipation					0.5	٧
(di/dt) <sub>cr</sub>	critical rate of rise of current	$T_{VJ} = 140 ^{\circ}\text{C}; f = 50 \text{Hz}$	•			150	A/μ
	$t_P = 200 \mu\text{s}; di_G/dt = 0.45 A/\mu\text{s};$						
			on-repet., $I_T = 50 A$			500	<u> </u>
$(dv/dt)_{cr}$	critical rate of rise of voltage	$V = \frac{2}{3} V_{DRM}$	$T_{VJ} = 140$ °C			1000	V/µ
		R <sub>GK</sub> = ∞; method 1 (linear volta	ge rise)				
<b>V</b> <sub>GT</sub>	gate trigger voltage	$V_D = 6 V$	$T_{VJ} = 25^{\circ}C$			1.5	١
			$T_{VJ} = -40$ °C			1.6	١
I <sub>GT</sub>	gate trigger current	$V_D = 6 V$	$T_{VJ} = 25^{\circ}C$			78	m
			$T_{VJ} = -40$ °C			200	m/
V <sub>GD</sub>	gate non-trigger voltage	$V_D = \frac{2}{3} V_{DRM}$	$T_{VJ} = 140^{\circ}C$			0.2	١
I <sub>GD</sub>	gate non-trigger current					5	m/
I <sub>L</sub>	latching current	t <sub>p</sub> = 10 μs	$T_{VJ} = 25$ °C			200	m
-	-	$I_{\rm G} = 0.45  \text{A};  \text{di}_{\rm G}/\text{dt} = 0.45  \text{A}/\mu \text{s}$					
I <sub>H</sub>	holding current	$V_D = 6 \text{ V } R_{GK} = \infty$	$T_{VJ} = 25$ °C			100	m
т <sub>gd</sub>	gate controlled delay time	$V_{D} = \frac{1}{2} V_{DRM}$	$T_{VJ} = 25 ^{\circ}\text{C}$			2	μ
<b>∙</b> gd	gato controlled dolay time	$I_{G} = 0.45 \text{ A}; \text{ di}_{G}/\text{dt} = 0.45 \text{ A}/\mu\text{s}$				_	μ
	turn-off time				150		
tq	taiti-on time	$V_R = 100 \text{ V}; I_T = 50 \text{A}; V = \frac{2}{3}$	3 V <sub>DRM</sub> I <sub>VJ</sub> = I25 U		150		μ



## **MCMA50P1600TA**

Package	Package TO-240AA			Ratings				
Symbol	Definition	Conditions			min.	typ.	max.	Unit
I <sub>RMS</sub>	RMS current	per terminal					100	Α
T <sub>VJ</sub>	virtual junction temperature	e			-40		140	°C
T <sub>op</sub>	operation temperature				-40		125	°C
T <sub>stg</sub>	storage temperature				-40		125	°C
Weight						81		g
M <sub>D</sub>	mounting torque				2.5		4	Nm
$\mathbf{M}_{_{T}}$	terminal torque				2.5		4	Nm
d <sub>Spp/App</sub>	anno aliata anno an arriform I atribina aliat	ace   striking distance through air	terminal to terminal	13.0	9.7			mm
d <sub>Spb/Apb</sub>	creepage distance on suna	ace   striking distance through an	terminal to backside	16.0	16.0			mm
V <sub>ISOL</sub>	isolation voltage	t = 1 second			4800			٧
1002	t = 1 minute		50/60 Hz, RMS; IsoL ≤ 1 mA		4000			٧



#### Part description

M = Module
C = Thyristor (SCR)
M = Thyristor
A = (up to 1800V)
50 = Current Rating [A]
P = Phase leg

1600 = Reverse Voltage [V]

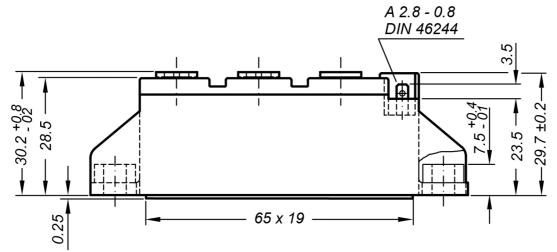
TA = TO-240AA-1B

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MCMA50P1600TA	MCMA50P1600TA	Box	36	513950

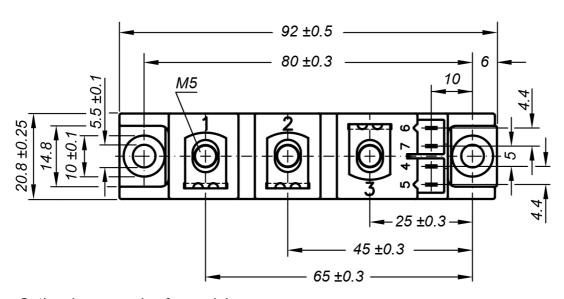
Equiva	lent Circuits for	Simulation	* on die level	$T_{VJ} = 140^{\circ}C$
$I \rightarrow V_0$	)—[R <sub>o</sub> ]-	Thyristor		
V <sub>0 max</sub>	threshold voltage	0.89		V
$R_{0 max}$	slope resistance *	4.1		$m\Omega$



#### **Outlines TO-240AA**



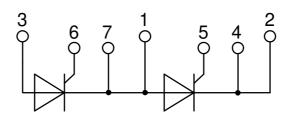
General tolerance: DIN ISO 2768 class "c"



Optional accessories for modules

Keyed gate/cathode twin plugs with wire length = 350 mm, gate = white, cathode = red Type ZY 200L (L = Left for pin pair 4/5)

Type ZY 200L (L = Left for pin pair 4/5) Type ZY 200R (R = Right for pin pair 6/7) UL 758, style 3751







#### **Thyristor**

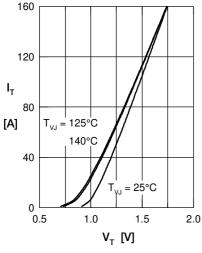


Fig. 1 Forward characteristics

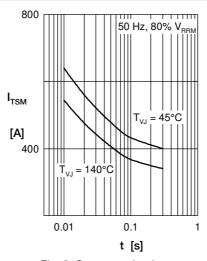


Fig. 2 Surge overload current  $I_{TSM}$ : crest value, t: duration

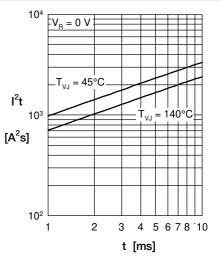


Fig. 3 I<sup>2</sup>t versus time (1-10 s)

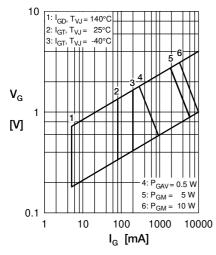


Fig. 4 Gate voltage & gate current

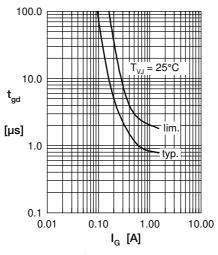


Fig. 5 Gate controlled delay time t<sub>ad</sub>

0.80

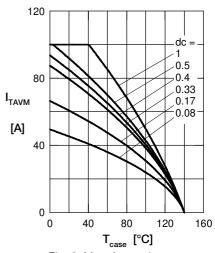


Fig. 6 Max. forward current at case temperature

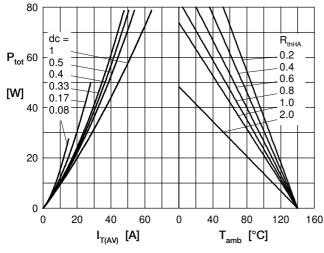


Fig. 7a Power dissipation versus direct output current Fig. 7b and ambient temperature

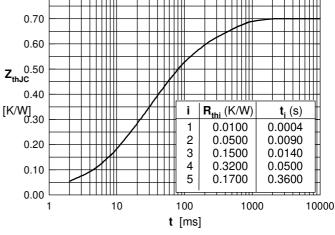


Fig. 8 Transient thermal impedance junction to case

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T2001N34TOF T901N35TOF T1080N02TOF T360N22TOF TZ810N22KOF T420N18TOF T420N14TOF TD305N16KOF T740N26TOF
T360N24TOF T430N16TOF T300N16TOF TD520N22KOF TT305N16KOF TT270N16KOF TD600N16KOF T740N22TOF T640N12TOF
T470N12TOF NTE5728 ETZ1100N16P70HPSA1 T430N18TOF TD700N22KOFHPSA1 T3441N52TOH T2851N48TOH
TD820N16KOFHPSA1 MCD501-16IO2 MCD501-18IO2 SK 100 KQ 12 SK 45 UT 16 SKKT 106B12 E SKKT 27/16E VSST180S12P0VPBF PSET132/16